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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

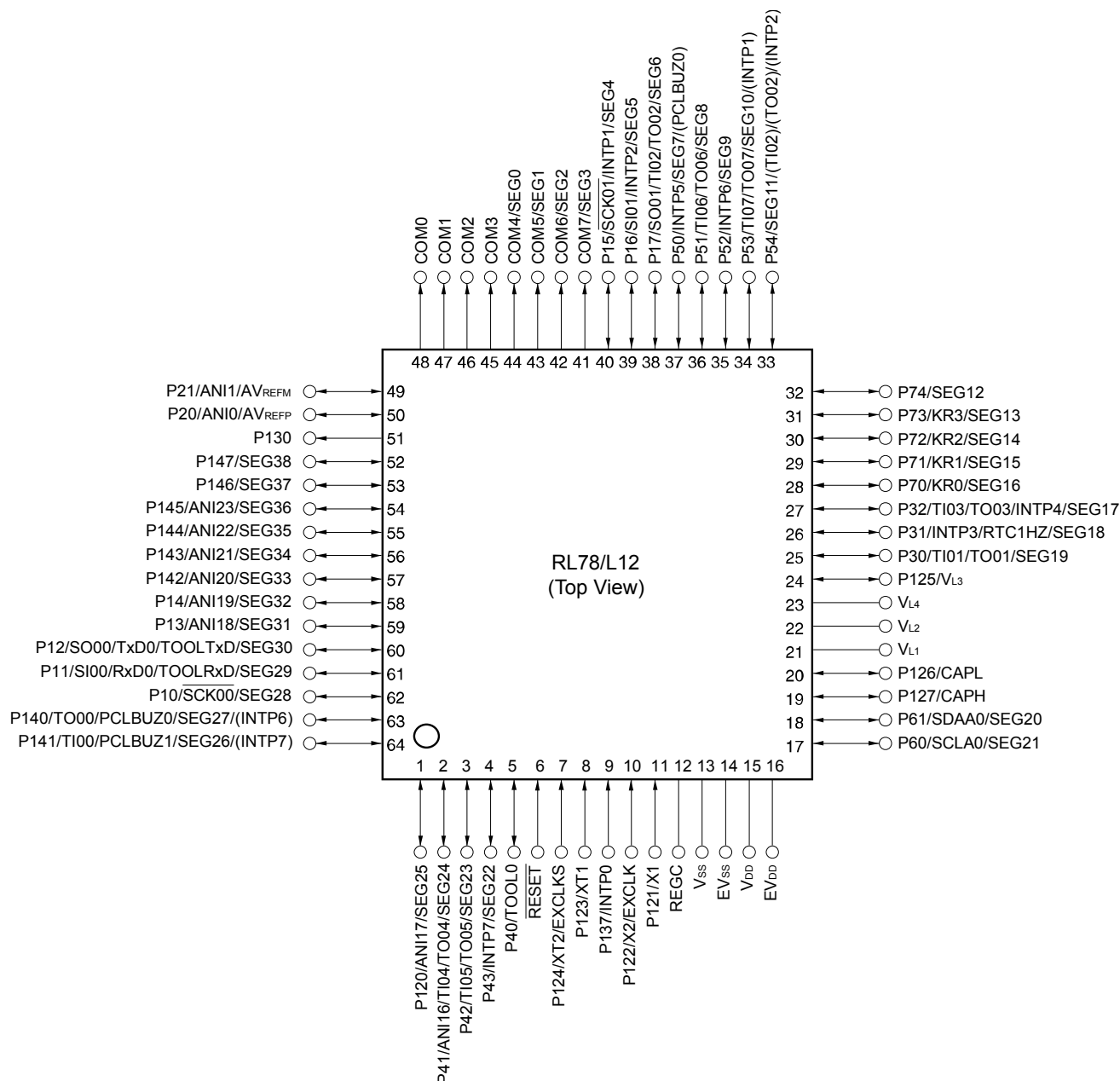
### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	33
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 9x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LFQFP (7x7)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10rg8afb-v0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10rg8afb-v0</a>

- 64-pin plastic LQFP (fine pitch) (10 × 10)
- 64-pin plastic LQFP (12 × 12)

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- Cautions**
1. Make EV<sub>ss</sub> pin the same potential as V<sub>ss</sub> pin.
  2. Make V<sub>DD</sub> pin the same potential as EV<sub>DD</sub> pin.
  3. Connect the REGC pin to V<sub>ss</sub> via a capacitor (0.47 to 1 μF).

- Remarks**
1. For pin identification, see 1.4 Pin Identification.
  2. When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub> and EV<sub>DD</sub> pins and connect the V<sub>ss</sub> and EV<sub>ss</sub> pins to separate ground lines.
  3. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR).

## 1.6 Outline of Functions

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

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Item		32-pin	44-pin	48-pin	52-pin	64-pin
		R5F10RBx	R5F10RFx	R5F10RGx	R5F10RJx	R5F10RLx
Code flash memory (KB)		8 to 32	8 to 32	8 to 32	8 to 32	16, 32
Data flash memory (KB)		2	2	2	2	2
RAM (KB)		1, 1.5 <sup>Note 1</sup>	1, 1.5 <sup>Note 1</sup>	1, 1.5 <sup>Note 1</sup>	1, 1.5 <sup>Note 1</sup>	1, 1.5 <sup>Note 1</sup>
Memory space		1 MB				
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) operation: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) operation: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) operation: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) operation: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)				
	High-speed on-chip oscillator clock	HS (high-speed main) operation: 1 to 24 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) operation: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) operation: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) operation: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)				
Subsystem clock		–	XT1 (crystal) oscillation , external subsystem clock input (EXCLKS) 32.768 kHz (TYP.): V <sub>DD</sub> = 1.6 to 5.5 V			
Low-speed on-chip oscillator clock		Internal oscillation 15 kHz (TYP.): V <sub>DD</sub> = 1.6 to 5.5 V				
General-purpose register		8 bits × 32 registers (8 bits × 8 registers × 4 banks)				
Minimum instruction execution time		0.04167 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 24 MHz operation)				
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)				
		30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)				
Instruction set		<ul style="list-style-type: none"><li>• Data transfer (8/16 bits)</li><li>• Adder and subtractor/logical operation (8/16 bits)</li><li>• Multiplication (8 bits × 8 bits)</li><li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li></ul>				
Total number of I/O port pins and pins dedicated to drive an LCD		28	40	44	48	58
I/O port	Total	20	29	33	37	47
	CMOS I/O	15	22	26	30	39
	CMOS input	3	5	5	5	5
	CMOS output	–	–	–	–	1
	N-ch open-drain I/O (EV <sub>DD</sub> tolerance)	2	2	2	2	2
Pins dedicated to drive an LCD		8	11	11	11	11
LCD controller/driver		Internal voltage boosting method, capacitor split method, and external resistance division method are switchable.				
Segment signal output		13	22 (18) <sup>Note 2</sup>	26 (22) <sup>Note 2</sup>	30 (26) <sup>Note 2</sup>	39 (35) <sup>Note 2</sup>
Common signal output		4	4 (8) <sup>Note 2</sup>			

**Notes** 1. In the case of the 1 KB, and 1.5 KB, this is 630 bytes when the self-programming function and data flash function is used.

2. The values in parentheses are the number of signal outputs when 8 com is used.

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Item		32-pin	44-pin	48-pin	52-pin	64-pin
		R5F10RBx	R5F10RFx	R5F10RGx	R5F10RJx	R5F10RLx
Timer	16-bit timer	8 channels	8 channels (with 1 channel remote control output function)			
	Watchdog timer	1 channel				
	Real-time clock (RTC)	1 channel				
	12-bit interval timer (IT)	1 channel				
	Timer output	4 channels (PWM outputs: 3 <sup>Note 1</sup> )	5 channels (PWM outputs: 4 <sup>Note 1</sup> )	6 channels (PWM outputs: 5 <sup>Note 1</sup> )	8 channels (PWM outputs: 7 <sup>Note 1</sup> )	
	RTC output	–	1 • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz or )			
Clock output/buzzer output		1	2			
		• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f <sub>MAIN</sub> = 20 MHz operation) • 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)				
8/10-bit resolution A/D converter		4 channels	7 channels	9 channels	10 channels	10 channels
Serial interface		• CSI: 2 channel/UART (LIN-bus supported): 1 channel				
	I <sup>2</sup> C bus	1 channel	1 channel	1 channel	1 channel	1 channel
Multiplier and divider/multiply-accumulator		• 16 bits × 16 bits = 32 bits (Unsigned or signed) • 32 bits ÷ 32 bits = 32 bits (Unsigned) • 16 bits × 16 bits + 32 bits = 32 bits (Unsigned or signed)				
DMA controller		2 channels				
Vectored interrupt sources	Internal	23	23	23	23	23
	External	4	6	7	7	9
Key interrupt		4				
Reset		• Reset by $\overline{\text{RESET}}$ pin • Internal reset by watchdog timer • Internal reset by power-on-reset • Internal reset by voltage detector • Internal reset by illegal instruction execution <sup>Note 2</sup> • Internal reset by RAM parity error • Internal reset by illegal-memory access				
Power-on-reset circuit		• Power-on-reset: 1.51 ±0.04 V • Power-down-reset: 1.50 ±0.04 V				
Voltage detector		• Rising edge : 1.67 V to 4.06 V (14 stages) • Falling edge : 1.63 V to 3.98 V (14 stages)				
On-chip debug function		Provided				
Power supply voltage		V <sub>DD</sub> = 1.6 to 5.5 V				
Operating ambient temperature		T <sub>A</sub> = –40 to +85 °C				

**Notes** 1. The number of PWM outputs varies depending on the setting of channels in use (the number of masters and slaves).

2. The illegal instruction is generated when instruction code FFH is executed.

Reset by the illegal instruction execution not issued by emulation with the in-circuit emulator or on-chip debug emulator.

## 2.3 DC Characteristics

## 2.3.1 Pin characteristics

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

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Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	Per pin for P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P130, P140 to P147				-10.0 Note 2	mA
		Total of P10 to P14, P40 to P43, P120, P130, P140 to P147 (When duty = 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V			-40.0	mA
			2.7 V ≤ EV <sub>DD</sub> < 4.0 V			-8.0	mA
			1.8 V ≤ EV <sub>DD</sub> < 2.7 V			-4.0	mA
			1.6 V ≤ EV <sub>DD</sub> < 1.8 V			-2.0	mA
		Total of P15 to P17, P30 to P32, P50 to P54, P70 to P74, P125 to P127 (When duty = 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V			-60.0	mA
			2.7 V ≤ EV <sub>DD</sub> < 4.0 V			-15.0	mA
			1.8 V ≤ EV <sub>DD</sub> < 2.7 V			-8.0	mA
			1.6 V ≤ EV <sub>DD</sub> < 1.8 V			-4.0	mA
		Total of all pins (When duty = 70% <sup>Note 3</sup> )				-100.0	mA
	I <sub>OH2</sub>	P20, P21	Per pin			-0.1	mA
		Total of all pins		1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V		-0.2	mA

- Notes**
1. Value of current at which the device operation is guaranteed even if the current flows from the V<sub>DD</sub> and EV<sub>DD</sub> pins to an output pin.
  2. Do not exceed the total current value.
  3. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OH</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OH</sub> = -40.0 mA

$$\text{Total output current of pins} = (-40.0 \times 0.7)/(80 \times 0.01) \cong -35.0 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Caution** P10, P12, P15, and P17 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS</sub> = 0 V)

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Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input voltage, high	V <sub>IH1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P140 to P147	Normal input buffer	0.8E <sub>VDD</sub>		E <sub>VDD</sub>	V
	V <sub>IH2</sub>	P10, P11, P15, P16	TTL input buffer 4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V	2.2		E <sub>VDD</sub>	V
			TTL input buffer 3.3 V ≤ E <sub>VDD</sub> < 4.0 V	2.0		E <sub>VDD</sub>	V
			TTL input buffer 1.6 V ≤ E <sub>VDD</sub> < 3.3 V	1.50		E <sub>VDD</sub>	V
	V <sub>IH3</sub>	P20, P21		0.7V <sub>DD</sub>		V <sub>DD</sub>	V
	V <sub>IH4</sub>	P60, P61		0.7E <sub>VDD</sub>		E <sub>VDD</sub>	V
	V <sub>IH5</sub>	P121 to P124, P137, EXCLK, EXCLKS, RESET		0.8V <sub>DD</sub>		V <sub>DD</sub>	V
Input voltage, low	V <sub>IL1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P140 to P147	Normal input buffer	0		0.2E <sub>VDD</sub>	V
	V <sub>IL2</sub>	P10, P11, P15, P16	TTL input buffer 4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V	0		0.8	V
			TTL input buffer 3.3 V ≤ E <sub>VDD</sub> < 4.0 V	0		0.5	V
			TTL input buffer 1.6 V ≤ E <sub>VDD</sub> < 3.3 V	0		0.32	V
	V <sub>IL3</sub>	P20, P21		0		0.3V <sub>DD</sub>	V
	V <sub>IL4</sub>	P60, P61		0		0.3E <sub>VDD</sub>	V
	V <sub>IL5</sub>	P121 to P124, P137, EXCLK, EXCLKS, RESET		0		0.2V <sub>DD</sub>	V

**Caution** The maximum value of V<sub>IH</sub> of P10, P12, P15, P17 is E<sub>VDD</sub>, even in the N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS</sub> = 0 V)

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Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage, high	V <sub>OH1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P130, P140 to P147	4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OH1</sub> = -10 mA	E <sub>VDD</sub> -1.5		V
			4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OH1</sub> = -3.0 mA	E <sub>VDD</sub> -0.7		V
			2.7 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OH1</sub> = -2.0 mA	E <sub>VDD</sub> -0.6		V
			1.8 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OH1</sub> = -1.5 mA	E <sub>VDD</sub> -0.5		V
			1.6 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OH1</sub> = -1.0 mA	E <sub>VDD</sub> -0.5		V
	V <sub>OH2</sub>	P20, P21	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V, I <sub>OH2</sub> = -100 μA	V <sub>DD</sub> -0.5		V
Output voltage, low	V <sub>OL1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P130, P140 to P147	4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL1</sub> = 20 mA		1.3	V
			4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL1</sub> = 8.5 mA		0.7	V
			2.7 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL1</sub> = 3.0 mA		0.6	V
			2.7 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL1</sub> = 1.5 mA		0.4	V
			1.8 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL1</sub> = 0.6 mA		0.4	V
			1.6 V ≤ E <sub>VDD</sub> < 5.5 V, I <sub>OL1</sub> = 0.3 mA		0.4	V
	V <sub>OL2</sub>	P20, P21	1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V, I <sub>OL2</sub> = 400 μA		0.4	V
	V <sub>OL3</sub>	P60, P61	4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL3</sub> = 15.0 mA		2.0	V
			4.0 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL3</sub> = 5.0 mA		0.4	V
			2.7 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL3</sub> = 3.0 mA		0.4	V
			1.8 V ≤ E <sub>VDD</sub> ≤ 5.5 V, I <sub>OL3</sub> = 2.0 mA		0.4	V
			1.6 V ≤ E <sub>VDD</sub> < 5.5 V, I <sub>OL3</sub> = 1.0 mA		0.4	V

**Caution** P10, P12, P15, P17 do not output high level in N-ch open-drain mode.**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 2.3.2 Supply current characteristics

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS</sub> = 0 V)

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Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current Note 1	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		1.5		mA
						V <sub>DD</sub> = 3.0 V		1.5		mA
				f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		3.3	5.0	mA
						V <sub>DD</sub> = 3.0 V		3.3	5.0	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		2.5	3.7	mA
						V <sub>DD</sub> = 3.0 V		2.5	3.7	mA
			LV (low-voltage main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 4 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.2	1.8	mA
						V <sub>DD</sub> = 2.0 V		1.2	1.8	mA
			HS (high-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.8	4.4	mA
						Resonator connection		3.0	4.6	mA
				f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		2.8	4.4	mA
						Resonator connection		3.0	4.6	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		1.8	2.6	mA
						Resonator connection		1.8	2.6	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.8	2.6	mA
						Resonator connection		1.8	2.6	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	mA
				f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.1	1.7	mA
						Resonator connection		1.1	1.7	mA
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = -40°C	Normal operation	Square wave input		3.5	4.9	μA
						Resonator connection		3.6	5.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +25°C	Normal operation	Square wave input		3.6	4.9	μA
						Resonator connection		3.7	5.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +50°C	Normal operation	Square wave input		3.7	5.5	μA
						Resonator connection		3.8	5.6	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +70°C	Normal operation	Square wave input		3.8	6.3	μA
						Resonator connection		3.9	6.4	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +85°C	Normal operation	Square wave input		4.1	7.7	μA
						Resonator connection		4.2	7.8	μA

(Notes and Remarks are listed on the next page.)



- Notes**
1. Total current flowing into  $V_{DD}$  and  $EV_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD}$  or  $V_{SS}$ ,  $EV_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer, watchdog timer, and LCD controller/driver.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }24\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$   
LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$   
LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks 1.**  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
2.  $f_{IH}$ : High-speed on-chip oscillator clock frequency
3.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

## (4) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

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(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Transfer rate		Transmission	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V			Note 1		Note 1	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 1.4 kΩ, V <sub>b</sub> = 2.7 V			2.8 <sup>Note 2</sup>		2.8 <sup>Note 2</sup>	Mbps
			2.7 V ≤ EV <sub>DD</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V			Note 3		Note 3	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ, V <sub>b</sub> = 2.3 V			1.2 <sup>Note 4</sup>		1.2 <sup>Note 4</sup>	Mbps
			2.4 V ≤ EV <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V			Note 6		Note 6	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V			0.43 <sup>Note 7</sup>		0.43 <sup>Note 7</sup>	Mbps
			1.8 V ≤ EV <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V				Notes 5, 6	Notes 5, 6	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V				0.43 <sup>Note 7</sup>	0.43 <sup>Note 7</sup>	Mbps

**Notes 1.** The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

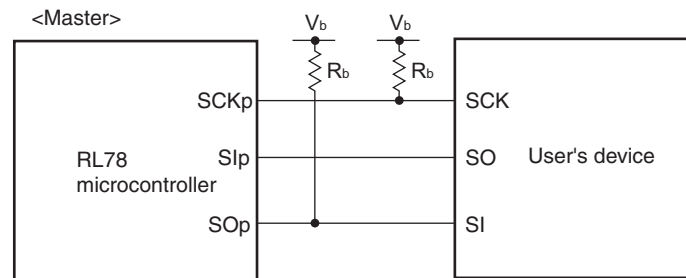
Expression for calculating the transfer rate when 4.0 V ≤ EV<sub>DD</sub> ≤ 5.5 V and 2.7 V ≤ V<sub>b</sub> ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

- 2.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.

**CSI mode connection diagram (during communication at different potential)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (SCKp, SOp) pull-up resistance,  $C_b[F]$ : Communication line (SCKp, SOp) load capacitance,  $V_b[V]$ : Communication line voltage
  2. p: CSI number ( $p = 00, 01$ ), m: Unit number ( $m = 0$ ), n: Channel number ( $n = 0, 1$ ), g: PIM and POM number ( $g = 1$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number ( $mn = 00, 01$ ))

- Notes**
1. This is the wait time from when voltage bucking is started (VLCON = 1) until display is enabled (LCDON = 1).
  2. This is a capacitor that is connected between voltage pins used to drive the LCD.
    - C1: A capacitor connected between CAPH and CAPL
    - C2: A capacitor connected between V<sub>L1</sub> and GND
    - C3: A capacitor connected between V<sub>L2</sub> and GND
    - C4: A capacitor connected between V<sub>L4</sub> and GND
- C1 = C2 = C3 = C4 = 0.47  $\mu$ F $\pm$ 30%

## 3.1 Absolute Maximum Ratings

Absolute Maximum Ratings (T<sub>A</sub> = 25°C)

(1/3)

Parameter	Symbols	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>	V <sub>DD</sub> = EV <sub>DD</sub>	-0.5 to +6.5	V
	EV <sub>DD</sub>	V <sub>DD</sub> = EV <sub>DD</sub>	-0.5 to +6.5	V
	EV <sub>SS</sub>		-0.5 to +0.3	V
REGC pin input voltage	V <sub>I REGC</sub>	REGC	-0.3 to +2.8 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 1</sup>	V
Input voltage	V <sub>I1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P140 to P147	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>I2</sub>	P60, P61 (N-ch open-drain)	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>I3</sub>	P20, P21, P121 to P124, P137, EXCLK, EXCLKS, RESET	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Output voltage	V <sub>O1</sub>	P10 to P17, P30 to P32, P40 to P43, P50 to P54, P60, P61, P70 to P74, P120, P125 to P127, P130, P140 to P147	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
	V <sub>O2</sub>	P20, P21	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note 2</sup>	V
Analog input voltage	V <sub>AI1</sub>	ANI16 to ANI23	-0.3 to EV <sub>DD</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V
	V <sub>AI2</sub>	ANI0, ANI1	-0.3 to V <sub>DD</sub> + 0.3 and -0.3 to AV <sub>REF</sub> (+) + 0.3 <sup>Notes 2, 3</sup>	V

**Notes 1.** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

**2.** Must be 6.5 V or lower.

**3.** Do not exceed AV<sub>REF</sub>(+) + 0.3 V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remarks 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**2.** AV<sub>REF</sub>(+) : + side reference voltage of the A/D converter.

**3.** V<sub>SS</sub> : Reference voltage

## 3.3 DC Characteristics

## 3.3.1 Pin characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

(1/5)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	Per pin for P10 to P17, P30 to P32, P40 to P43, P50 to P54, P70 to P74, P120, P125 to P127, P130, P140 to P147				-3.0 <sup>Note 2</sup>	mA
		Total of P10 to P14, P40 to P43, P120, P130, P140 to P147 (When duty = 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V			-30.0	mA
			2.7 V ≤ EV <sub>DD</sub> < 4.0 V			-8.0	mA
			2.4 V ≤ EV <sub>DD</sub> < 2.7 V			-4.0	mA
		Total of P15 to P17, P30 to P32, P50 to P54, P70 to P74, P125 to P127 (When duty = 70% <sup>Note 3</sup> )	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V			-30.0	mA
			2.7 V ≤ EV <sub>DD</sub> < 4.0 V			-15.0	mA
			2.4 V ≤ EV <sub>DD</sub> < 2.7 V			-8.0	mA
		Total of all pins (When duty = 70% <sup>Note 3</sup> )				-60.0	mA
	I <sub>OH2</sub>	P20, P21	Per pin			-0.1	mA
			Total of all pins	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		-0.2	mA

**Notes** 1. Value of current at which the device operation is guaranteed even if the current flows from the V<sub>DD</sub> and EV<sub>DD</sub> pins to an output pin.

2. Do not exceed the total current value.

3. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OH</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OH</sub> = -30.0 mA

$$\text{Total output current of pins} = (-30.0 \times 0.7) / (80 \times 0.01) \approx -26.25 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Caution** P10, P12, P15, and P17 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

- Notes**
1. Total current flowing into V<sub>DD</sub> and EV<sub>DD</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD</sub> or V<sub>SS</sub>, EV<sub>SS</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. When high-speed on-chip oscillator and subsystem clock are stopped.
  3. When high-speed system clock and subsystem clock are stopped.
  4. When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, watchdog timer, and LCD controller/driver.
  5. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }24\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

(3/3)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	I <sub>FIL</sub> <sup>Note 1</sup>				0.20		μA
RTC operating current	I <sub>RTC</sub> Notes 1, 2, 3	f <sub>MAIN</sub> is stopped			0.08		μA
12-bit interval timer current	I <sub>IT</sub> Notes 1, 2, 4				0.08		μA
Watchdog timer operating current	I <sub>WDT</sub> Notes 1, 2, 5	f <sub>IL</sub> = 15 kHz			0.24		μA
A/D converter operating current	I <sub>ADC</sub> Notes 1, 6	When conversion at maximum speed	Normal mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 5.0 V		1.3	1.7	mA
			Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		0.5	0.7	mA
A/D converter reference voltage current	I <sub>ADREF</sub> Note 1				75.0		μA
Temperature sensor operating current	I <sub>TMPS</sub> Note 1				75.0		μA
LVD operating current	I <sub>LVD</sub> Notes 1, 7				0.08		μA
Self-programming operating current	I <sub>FSP</sub> Notes 1, 9				2.50	12.20	mA
BGO operating current	I <sub>BGO</sub> Notes 1, 8				2.50	12.20	mA
LCD operating current	I <sub>LCD1</sub> Notes 11, 12	External resistance division method	V <sub>DD</sub> = EV <sub>DD</sub> = 5.0 V V <sub>L4</sub> = 5.0 V		0.04	0.20	μA
	I <sub>LCD2</sub> Note 11	Internal voltage boosting method	V <sub>DD</sub> = EV <sub>DD</sub> = 5.0 V V <sub>L4</sub> = 5.1 V (VLCD = 12H)		1.12	3.70	μA
			V <sub>DD</sub> = EV <sub>DD</sub> = 3.0 V V <sub>L4</sub> = 3.0 V (VLCD = 04H)		0.63	2.20	μA
	I <sub>LCD3</sub> <sup>Note 11</sup>	Capacitor split method	V <sub>DD</sub> = EV <sub>DD</sub> = 3.0 V V <sub>L4</sub> = 3.0 V		0.12	0.50	μA
SNOOZE operating current	I <sub>SNOZ</sub> <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 10</sup>		0.50	1.10	mA
			The A/D conversion operations are performed, Low voltage mode, AV <sub>REFP</sub> = V <sub>DD</sub> = 3.0 V		1.20	2.04	mA
		CSI/UART operation			0.70	1.54	mA

(Notes and Remarks are listed on the next page.)



## (4) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)

(2/2)

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate		Transmission	4.0 V ≤ EV <sub>DD</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	<b>Note 1</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 1.4 kΩ, V <sub>b</sub> = 2.7 V	2.0 <sup>Note 2</sup>	Mbps
			2.7 V ≤ EV <sub>DD</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	<b>Note 3</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 kΩ, V <sub>b</sub> = 2.3 V	1.2 <sup>Note 4</sup>	Mbps
			2.4 V ≤ EV <sub>DD</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V	<b>Note 5</b>	bps
			Theoretical value of the maximum transfer rate C <sub>b</sub> = 50 pF, R <sub>b</sub> = 5.5 kΩ, V <sub>b</sub> = 1.6 V	0.43 <sup>Note 6</sup>	Mbps

**Notes 1.** The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ EV<sub>DD</sub> ≤ 5.5 V and 2.7 V ≤ V<sub>b</sub> ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

2. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 1 above to calculate the maximum transfer rate under conditions of the customer.

3. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ EV<sub>DD</sub> < 4.0 V and 2.3 V ≤ V<sub>b</sub> ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

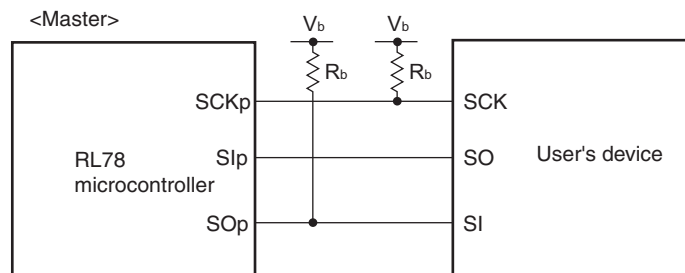
\* This value is the theoretical value of the relative difference between the transmission and reception sides.

4. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 3 above to calculate the maximum transfer rate under conditions of the customer.

- Notes** 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.  
 2. When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output ( $V_{DD}$  tolerance (32- to 52-pin products)/ $EV_{DD}$  tolerance (64-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

CSI mode connection diagram (during communication at different potential)



- Remarks** 1.  $R_b[\Omega]$ : Communication line (SCKp, SOp) pull-up resistance,  
 $C_b[\text{F}]$ : Communication line (SCKp, SOp) load capacitance,  $V_b[\text{V}]$ : Communication line voltage  
 2. p: CSI number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1),  
 g: PIM and POM number (g = 1)  
 3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

## 3.5.2 Serial interface IICA

(1) I<sup>2</sup>C standard mode(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Standard mode: 2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	100	kHz
		f <sub>CLK</sub> ≥ 1 MHz 2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	100	kHz
Setup time of restart condition	t <sub>SU:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.7		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.7		μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.0		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.0		μs
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.7		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.7		μs
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.0		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.0		μs
Data setup time (reception)	t <sub>SU:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	250		ns
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	250		ns
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	3.45	μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	0	3.45	μs
Setup time of stop condition	t <sub>SU:STO</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.0		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.0		μs
Bus-free time	t <sub>BUF</sub>	2.7 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.7		μs
		2.4 V ≤ EV <sub>DD</sub> ≤ 5.5 V	4.7		μs

**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.Standard mode: C<sub>b</sub> = 400 pF, R<sub>b</sub> = 2.7 kΩ

(2) When reference voltage (+) =  $AV_{REFP}/ANI0$  (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) =  $AV_{REFM}/ANI1$  (ADREFM = 1), target pin : ANI16 to ANI23

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ EV<sub>DD</sub> = V<sub>DD</sub> ≤ 5.5 V, 2.4 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution AV <sub>REFP</sub> = EV <sub>DD</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±5.0	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution AV <sub>REFP</sub> = EV <sub>DD</sub> = V <sub>DD</sub> <sup>Note 3</sup>	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875	39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution AV <sub>REFP</sub> = EV <sub>DD</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.35	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution AV <sub>REFP</sub> = EV <sub>DD</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.35	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution AV <sub>REFP</sub> = EV <sub>DD</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±3.5	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution AV <sub>REFP</sub> = EV <sub>DD</sub> = V <sub>DD</sub> <sup>Note 3</sup>	2.4 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±2.0	LSB
Analog input voltage	V <sub>AIN</sub>	ANI16 to ANI23	0		AV <sub>REFP</sub> and EV <sub>DD</sub>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When AV<sub>REFP</sub> < EV<sub>DD</sub> = V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±4.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.20%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±2.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

## 3.7.3 Capacitor split method

## 1/3 bias method

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
V <sub>L4</sub> voltage	V <sub>L4</sub>	C1 to C4 = 0.47 μF <sup>Note 2</sup>		V <sub>DD</sub>		V
V <sub>L2</sub> voltage	V <sub>L2</sub>	C1 to C4 = 0.47 μF <sup>Note 2</sup>	2/3 V <sub>L4</sub> - 0.1	2/3 V <sub>L4</sub>	2/3 V <sub>L4</sub> + 0.1	V
V <sub>L1</sub> voltage	V <sub>L1</sub>	C1 to C4 = 0.47 μF <sup>Note 2</sup>	1/3 V <sub>L4</sub> - 0.1	1/3 V <sub>L4</sub>	1/3 V <sub>L4</sub> + 0.1	V
Capacitor split wait time <sup>Note 1</sup>	t <sub>WAIT</sub>		100			ms

**Notes** 1. This is the wait time from when voltage bucking is started (VLCON = 1) until display is enabled (LCDON = 1).

2. This is a capacitor that is connected between voltage pins used to drive the LCD.

C1: A capacitor connected between CAPH and CAPL

C2: A capacitor connected between V<sub>L1</sub> and GND

C3: A capacitor connected between V<sub>L2</sub> and GND

C4: A capacitor connected between V<sub>L4</sub> and GND

C1 = C2 = C3 = C4 = 0.47 μF±30%